

## KSC2001

### **General Purpose Applications**

High h<sub>FE</sub> and Low V<sub>CE</sub> (sat)



### 1. Emitter 2. Collector 3. Base

## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	700	mA
I <sub>B</sub>	Base Current	150	mA
P <sub>C</sub>	Collector Power Dissipation	600	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>BE</sub> (on)	* Base Emitter On Voltage	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA	600	640	700	mV
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_{E}$ =0			100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}=5V$ , $I_{C}=0$			100	nA
h <sub>FE1</sub>	* DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	90	200	400	
h <sub>FE2</sub>		V <sub>CE</sub> =1V, I <sub>C</sub> =700mA	50	140		
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> =700mA, I <sub>B</sub> =70mA		0.2	0.6	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> =700mA, I <sub>B</sub> =70mA		0.95	1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		13	25	pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA	50	170		MHz

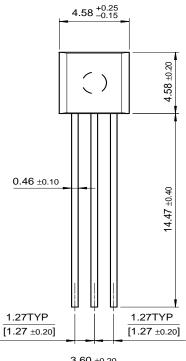
### \* Pulse test: PW≤350μs, Duty cycle≤2%

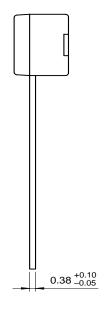
### **h**<sub>FE</sub> Classification

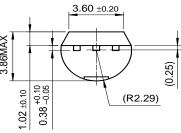
Classification	0	Y	G
h <sub>FE1</sub>	90 ~ 180	135 ~ 270	200 ~ 400

# **Package Dimensions**

TO-92







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EnSigna™	$I^2C^{TM}$	OCXTM	RapidConfigure™	UHC™
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Rev. I1

### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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